## 65 V, 100 mA NPN general-purpose transistors

Rev. 9 — 25 September 2012

**Product data sheet** 

### 1. Product profile

### 1.1 General description

NPN general-purpose transistors in Surface-Mounted Device (SMD) plastic packages.

#### Table 1. Product overview

Type number <sup>[1]</sup>	Package			PNP complement
	NXP	JEITA	JEDEC	
BC846	SOT23	-	TO-236AB	BC856
BC846W	SOT323	SC-70	-	BC856W
BC846T	SOT416	SC-75	-	BC856T

[1] Valid for all available selection groups.

### 1.2 Features and benefits

- General-purpose transistors
- SMD plastic packages
- Two different gain selections

#### **1.3 Applications**

General-purpose switching and amplification

### 1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	65	V
I <sub>C</sub>	collector current		-	-	100	mA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 5 V; $I_C$ = 2 mA	110	-	450	
	h <sub>FE</sub> group A		110	180	220	
	h <sub>FE</sub> group B		200	290	450	



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### 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
SOT23, S	SOT323, SOT416		
1	base		_
2	emitter		3
3	collector	12	1

## 3. Ordering information

Table 4. Order	ring inforn	nation	
Type number <sup>[1]</sup>	Package		
	Name	Description	Version
BC846	-	plastic surface-mounted package; 3 leads	SOT23
BC846W	SC-70	plastic surface-mounted package; 3 leads	SOT323
BC846T	SC-75	plastic surface-mounted package; 3 leads	SOT416

[1] Valid for all available selection groups.

## 4. Marking

Table 5. Marking codes	
Type number	Marking code <sup>[1]</sup>
BC846	1D*
BC846A	1A*
BC846B	1B*
BC846W	1D*
BC846AW	1A*
BC846BW	1B*
BC846T	1M
BC846AT	1A
BC846BT	1B

[1] \* = placeholder for manufacturing site code

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## 5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	80	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	65	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	6	V
I <sub>C</sub>	collector current		-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	200	mA
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms	-	200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u>		
	SOT23		-	250	mW
	SOT323		-	200	mW
	SOT416		-	150	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

## 6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	SOT23		-	-	500	K/W
	SOT323		-	-	625	K/W
	SOT416		-	-	833	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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## 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}$		-	-	15	nA
	current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$		-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_C = 0 \text{ A}$		-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 5 V; $I_C$ = 10 $\mu$ A					
	h <sub>FE</sub> group A			-	180	-	
	h <sub>FE</sub> group B			-	290	-	
	DC current gain	$V_{CE} = 5 \text{ V}; I_C = 2 \text{ mA}$		110	-	450	
	h <sub>FE</sub> group A			110	180	220	
	h <sub>FE</sub> group B			200	290	450	
OLGAI	collector-emitter	$I_{C}$ = 10 mA; $I_{B}$ = 0.5 mA		-	90	200	mV
	saturation voltage	$I_{C}$ = 100 mA; $I_{B}$ = 5 mA	[1]	-	200	400	mV
V <sub>BEsat</sub>	base-emitter	$I_{C}$ = 10 mA; $I_{B}$ = 0.5 mA	[2]	-	760	-	mV
	saturation voltage	$I_{C} = 100 \text{ mA}; I_{B} = 5 \text{ mA}$	[2]	-	900	-	mV
V <sub>BE</sub>	base-emitter voltage	$I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$	[3]	580	660	700	mV
		$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}$	[3]	-	-	770	mV
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; f = 100 MHz		100	-	-	MHz
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V};  \text{I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$		-	2	3	pF
C <sub>e</sub>	emitter capacitance	$\label{eq:Veb} \begin{array}{l} V_{EB}=0.5 \text{ V}; \text{ I}_{C}=\text{i}_{c}=0 \text{ A};\\ \text{f}=1 \text{ MHz} \end{array}$		-	11	-	pF
NF	noise figure	$I_C = 200 \ \mu$ A; V <sub>CE</sub> = 5 V; R <sub>S</sub> = 2 kΩ; f = 1 kHz; B = 200 Hz		-	2	10	dB

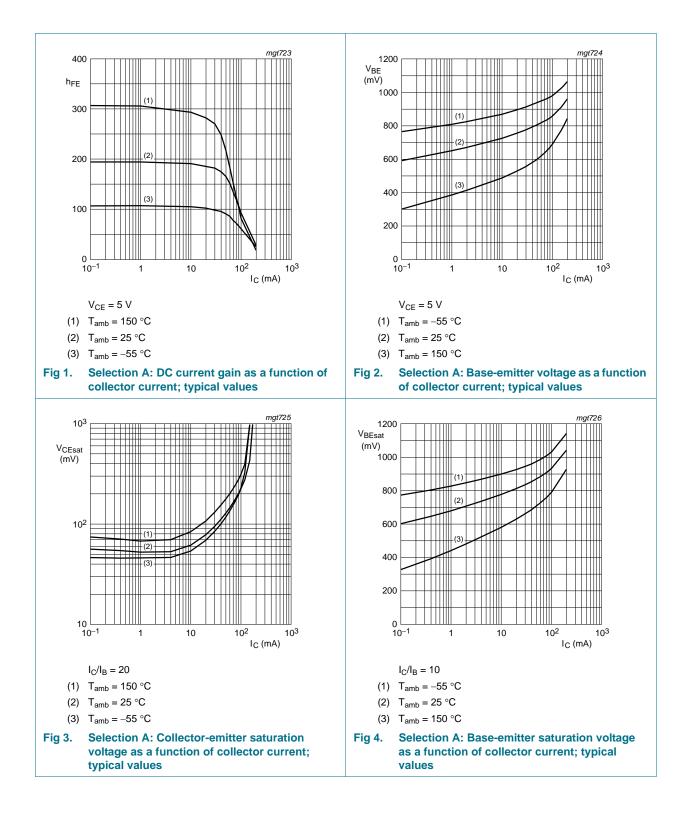
[2] V<sub>BEsat</sub> decreases by approximately 1.7 mV/K with increasing temperature.

[3]  $V_{BE}$  decreases by approximately 2 mV/K with increasing temperature.

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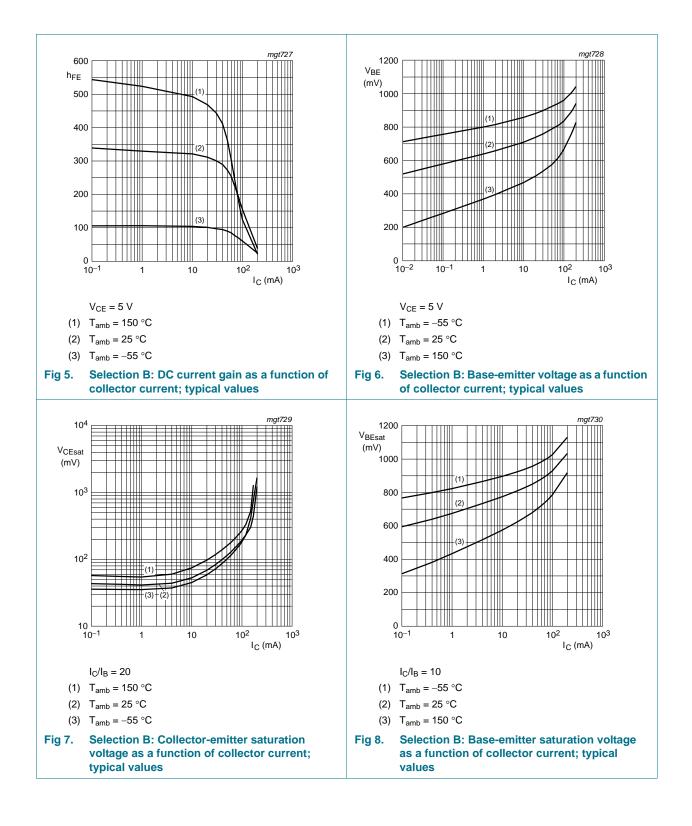
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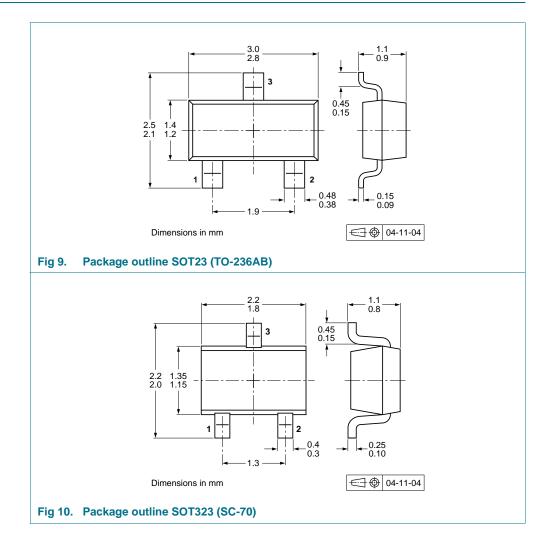
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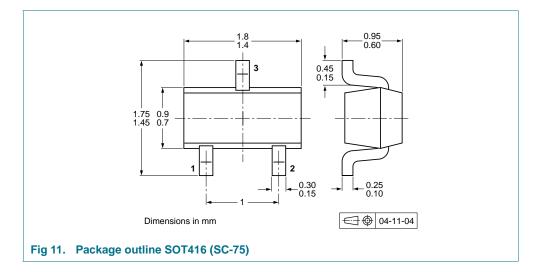
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## 8. Package outline



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## 9. Packing information

#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

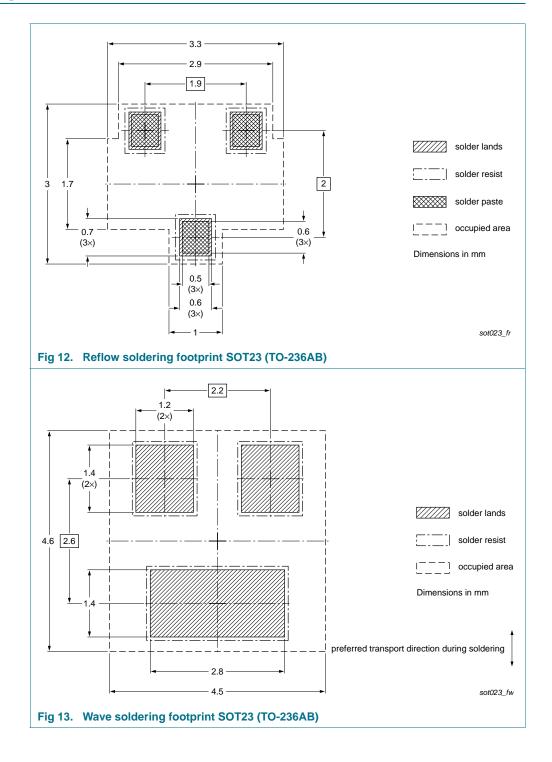
Туре	Package	Package Description		Packing quantity		
number <sup>[2]</sup>			1000	3000	4000	
BC846	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
BC846W	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	
BC846T	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	

[1] For further information and the availability of packing methods, see <u>Section 13</u>.

[2] Valid for all available selection groups.

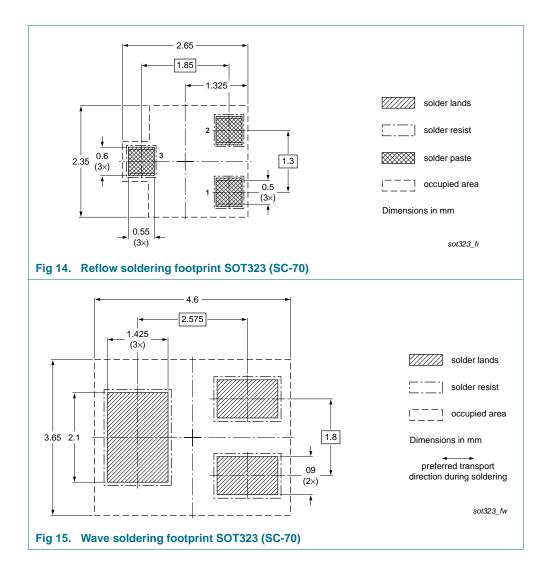
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## 10. Soldering



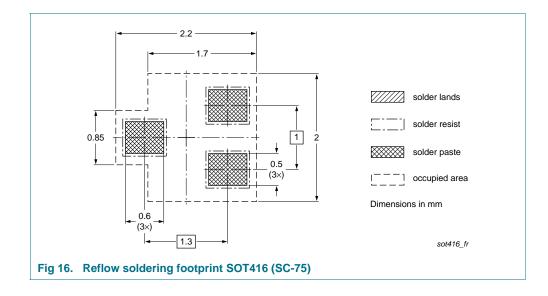
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## 11. Revision history

Release date	Data sheet status	Change notice	Supersedes
20120925	Product data sheet	-	BC846_SER v.8
• Table 6 "Lin	niting values": P <sub>tot</sub> values c	orrected	
20120424	Product data sheet		BC846_BC546_SER v.7
20091117	Product data sheet	-	BC846_BC546_SER v.6
20060207	Product data sheet	-	-
	20120925 • <u>Table 6 "Lir</u> 20120424 20091117	20120925 Product data sheet   • Table 6 "Limiting values": Ptot values of   20120424 Product data sheet   20091117 Product data sheet	20120925 Product data sheet -   • Table 6 "Limiting values": Ptot values corrected   20120424 Product data sheet   20091117 Product data sheet

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Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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